TOSHIBA Transistor Silicon NPN Epitaxial Type

## 2SC5738

# High-Speed Switching Applications DC-DC Converter Applications

- High DC current gain:  $h_{FE} = 400 \text{ to } 1000 \text{ (IC} = 0.5 \text{ A)}$
- Low collector-emitter saturation voltage: VCE (sat) = 0.15 V (max)
- High-speed switching:  $t_f = 90 \text{ ns (typ.)}$

### Maximum Ratings (Ta = 25°C)

| Charac                      | teristics | Symbol           | Rating     | Unit |  |
|-----------------------------|-----------|------------------|------------|------|--|
| Collector-base voltage      |           | V <sub>CBO</sub> | 40         | V    |  |
| Collector-emitter voltage   |           | V <sub>CEX</sub> | 30         | V    |  |
| Collector-emitter voltage   |           | V <sub>CEO</sub> | 20         | V    |  |
| Emitter-base voltage        |           | V <sub>EBO</sub> | 7          | V    |  |
| Collector current           | DC        | IC               | 3.5        | Α    |  |
|                             | Pulse     | I <sub>CP</sub>  | 6.0        |      |  |
| Base current                |           | ΙΒ               | 350        | mA   |  |
| Collector power dissipation | DC        | PC               | 625        | mW   |  |
|                             | t = 10 s  | (Note)           | 1000       |      |  |
| Junction temperature        |           | Tj               | 150        | °C   |  |
| Storage temperature range   |           | T <sub>stg</sub> | –55 to 150 | °C   |  |

Note: Mounted on an FR4 board (glass epoxy, 1.6 mm thick, Cu area: 645 mm²)

# 1. Base 2. Emitter 3. Collector JEDEC — JEITA — TOSHIBA 2-3S1A

Weight: 0.01 g (typ.)

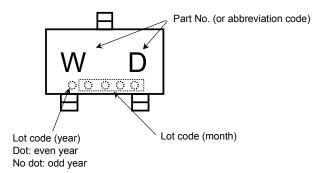
### **Electrical Characteristics (Ta = 25°C)**

| Characteristics                      |              | Symbol                | Test Condition   | Min | Тур. | Max  | Unit |
|--------------------------------------|--------------|-----------------------|--|-----|------|------|------|
| Collector cut-off current            |              | I <sub>CBO</sub>      | $V_{CB} = 40 \text{ V}, I_{E} = 0$                       | _   | _    | 100  | nA   |
| Emitter cut-off current              |              | I <sub>EBO</sub>      | $V_{EB} = 7 \text{ V}, I_{C} = 0$                        | _   | _    | 100  | nA   |
| Collector-emitter breakdown voltage  |              | V <sub>(BR) CEO</sub> | $I_C = 10 \text{ mA}, I_B = 0$                           | 20  | _    | _    | V    |
| DC current gain                      |              | h <sub>FE</sub> (1)   | V <sub>CE</sub> = 2 V, I <sub>C</sub> = 0.5 A            | 400 | _    | 1000 |      |
|                                      |              | h <sub>FE</sub> (2)   | V <sub>CE</sub> = 2 V, I <sub>C</sub> = 1.6 A            | 200 | _    | _    |      |
| Collector-emitter saturation voltage |              | V <sub>CE (sat)</sub> | $I_C = 1.6 \text{ A}, I_B = 32 \text{ mA}$               | _   | _    | 0.15 | V    |
| Base-emitter saturation voltage      |              | V <sub>BE (sat)</sub> | $I_C = 1.6 \text{ A}, I_B = 32 \text{ mA}$               | _   | _    | 1.10 | V    |
| Collector output capacitance         |              | C <sub>ob</sub>       | V <sub>CB</sub> = 10 V, I <sub>E</sub> = 0, f = 1 MHz    | _   | 18   | _    | pF   |
| Switching time                       | Rise time    | t <sub>r</sub>        | See Figure 1.  | _   | 100  | _    |      |
|                                      | Storage time | t <sub>stg</sub>      | $V_{CC} \simeq 12 \text{ V}, \text{ R}_{L} = 7.5 \Omega$ | _   | 350  | _    | ns   |
|                                      | Fall time    | t <sub>f</sub>        | $I_{B1} = -I_{B2} = 53 \text{ mA}$                       | _   | 90   | _    |      |

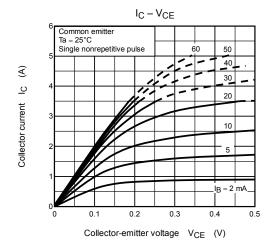
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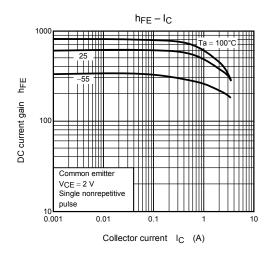
Figure 1 Switching Time Test Circuit & Timing Chart

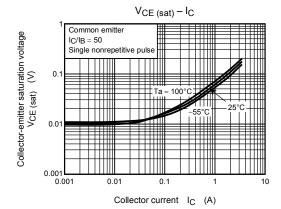
### Marking

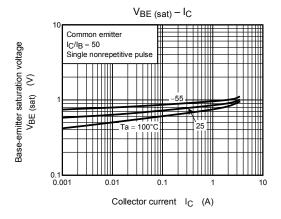


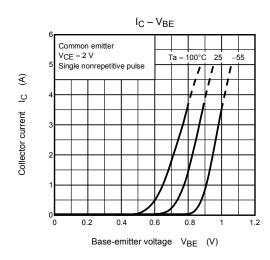
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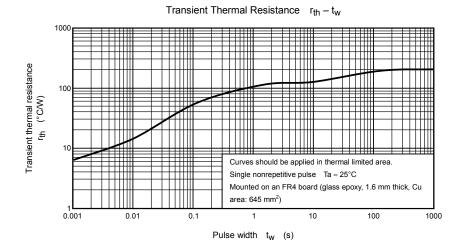


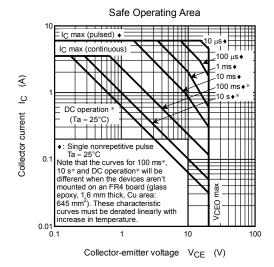






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